Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Plastic

Overall Length:

Between 0.150 inches and 0.175 inches

Terminal Length:

1.000 inches

Overall Diameter:

Between 0.068 inches and 0.076 inches

Mounting Method:

Terminal

Features Provided:

Burn in

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

20.0 breakdown voltage, instantaneous

Current Rating Per Characteristic:

10.00 microamperes collector current, dc peak and 35.00 milliamperes all primaries preset

Power Rating Per Characteristic:

125.0 milliwatts any acceptable preset

Capacitance Rating In Picofarads:

1.2

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius ambient air

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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